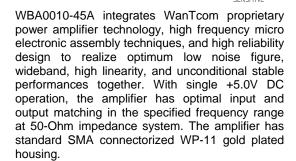
## **Key Features**



#### 10 MHz ~ 1.0 GHz

- +/-0.25 dB Gain Flatness
- 20.0 dBm Output P<sub>1dB</sub>
- 45.0 dB Gain
- 0.60 dB Noise Figure
- 1.35:1 VSWR
- 35.0 dBm output IP<sub>3</sub>
- >34 years MTBF
- Unconditional stable
- RoHS compliant
- Meet MIL-STD-202

### **Product Description**



## **Applications**

- Mobile Infrastructures
- Cellular
- Paging System
- Measurement
- Fixed Wireless



### **Specifications**

Summary of the electrical specifications WBA0010-45A at room temperature

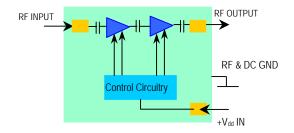
Index	Testing Item	Symbol	Test Constraints	Min	Nom	Max	Unit
1	Gain	S <sub>21</sub>	10 MHz – 1.0 GHz	43	45		dB
2	Gain Variation	ΔG	10 MHz – 1.0 GHz		+/- 0.25	+/-0.5	dB
3	Input VSWR	SWR <sub>1</sub>	10 MHz – 1.0 GHz		1.35:1	1.5:1	Ratio
4	Output VSWR	SWR <sub>2</sub>	10 MHz – 1.0 GHz		1.35:1	1.5:1	Ratio
5	Noise Figure	NF	10 MHz – 50 MHz		1.0	1.5	dB
			50 MHz – 1.0 GHz		0.60	0.8	
6	Reverse Isolation	S <sub>12</sub>	10 MHz – 1.0 GHz	40	50		dB
7	Output IP <sub>3</sub>	IP <sub>3</sub>	10 MHz – 1.0 GHz	30	35		dBm
8	Output Power 1dB compression Point	P <sub>1dB</sub>	10 MHz – 1.0 GHz	19	20		dBm
9	Current Consumption	I <sub>dd</sub>	V <sub>dd</sub> = +5.0 V		100		mA
10	Power Supply Voltage	$V_{dd}$		+4.7	+5	+5.3	V
11	Operating Temperature	To		-40		+85	°C
12	Maximum Average RF Input Power	P <sub>IN, MAX</sub>	DC – 6 GHz			10	dBm

### **Absolute Maximum Ratings**

Parameters	Units	Ratings
DC Power Supply Voltage	V	6
Drain Current	mA	140
Total Power Dissipation	W	0.7
RF Input Power	dBm	10
Channel Temperature	°C	150
Storage Temperature	°C	-55 ~ 125
Operating Temperature	°C	-40 ~ 85
Thermal Resistance	°C/W	120

Operation of this device above any one of these parameters may cause permanent damage.

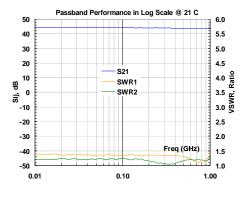
## **Functional Block Diagram**

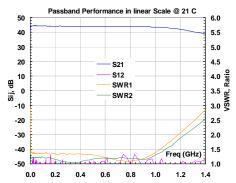


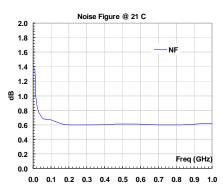
## **Ordering Information**

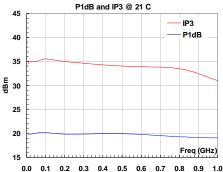
Model Number	WBA0010-45A
MOUGH MUHIDEI	1 11 DAUG 10-43A

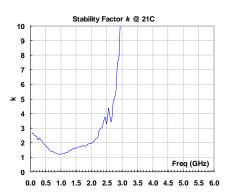
# **Typical Data:**











## **Outline, WP-11 Housing**

UNITS: INCH [mm]

BODY: Brass
Finish: Gold Plating
RF Connector: SMA F Gold Field

Replaceable V<sub>dd</sub> PWR: Feed through

0.27 ø0.125 [ø3.18] [6.86] [4.70] (<del>4</del>) (<del>4</del>) 0.325 IN WanTcom
Model: XXXXXXX
SN: [YYWWXxxx]
f=x.xdB, G=xx dB
NF=x.xdB,P]dB=xxdBm DUT 1.00 [Vdd] MADE IN USA Vdd\_IN (i) 0.240 [2.51]  $\bigcirc$ (4) 0.30 0.89 [7.62] 0.40 [22.61] 1.64 [10.16] [41.66] 0.540 [13.72] 0 (t) (47) Ø0.018 IN WanTcom

Model: XXXXXXXX
SN: [YYWWxxxx]
f=x.xdB, G=xx dB
NF=x.xdB,PldB=xxdBm 1 □UT 0.08 #2-56 UNC 2B DP: 0.20\*, (2X) [Vdd] MADE IN USA  $\bigcirc$  $\bigcirc$ (む)

### **Application Notes:**

#### A. SMA Torque Wrench Selection

Always use a torque wrench with  $5 \sim 6$  inch-lb coupling torque setting for mating the SMA cables to the amplifier. Never use torque more than 8 inch-lb wrench for tightening the mating cable to the connector. Otherwise, the permanent damage will occur to the SMA connectors of the amplifier. 8710-1582 (5 inch-lb) is one of the ideal torque wrench choice from Agilent Technology.

#### **B.** DC Power Line Connection

Strip the insulation layer at the end of DC power supply wire. The stripped distance should be in the range of 0.100" to 0.200". The 24 ~ 26 American Wire Gauge wire is suitable. Wound the stripped terminal wire about 1 to 2 turns on the DC feed thru center pin. Solder the wounded wire and the center pin together. Clean the soldering area by Q-tip with alcohol to remove the flux and residue.

Repeat the process to solder the DC return wire on the ground turret.

#### C. Mounting the Amplifier

Use three pieces of #4-40 with longer than 9/16" screws for mounting the amplifier on a metal-based chase. Flat and spring washers are needed to prevent the screw loosening during the shock and vibration. Always use the appropriate torque setting of the power screwdriver to mount them.

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